TSV91x Rail-to-Rail Input/Output, 8-MHz Operational Amplifiers

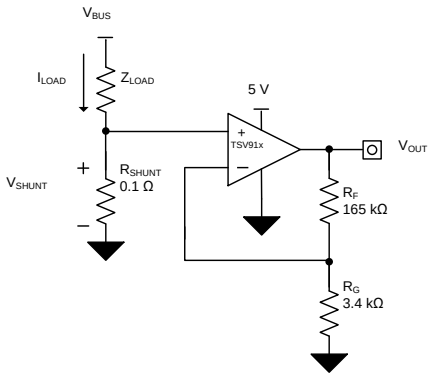
1 Features

- Rail-to-Rail Input and Output
- Low Noise: 18 nV/√Hz at 1 kHz
- Low Power Consumption: 550 µA (Typical)
- High-Gain Bandwidth: 8 MHz
- Operating Supply Voltage From 2.5 V to 5.5 V
- Low Input Bias Current: 1 pA (Typical)
- Low Input Offset Voltage: 1.9 mV (Maximum)
- Low Offset Voltage Drift: ±0.5 µV/°C (Typical)
- ESD Internal Protection: ±4 kV Human-Body Model (HBM)
- Extended Temperature Range: –40°C to +125°C

2 Applications

- Battery-Powered Applications
- Motor Control
- Power Modules
- HVAC: Heating, Ventilating, and Air Conditioning
- Washing Machines
- Refrigerators
- Medical Instrumentation
- Active Filters
- Sensor Signal Conditioning
- Audio Receiver
- Automotive Infotainment

Low-Side Motor Control



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3 Description

The TSV91x family, which includes single-, dual-, and quad-channel operational amplifiers (op amps), is specifically designed for general-purpose applications. Featuring rail-to-rail input and output (RRIO) swings, wide bandwidth (8 MHz), and low offset voltage (0.3 mV, typical), this family is attractive for a variety of applications that require a good balance between speed and power consumption. The op amps are unity-gain stable and feature an ultra-low input bias current, which enables the family to be used in applications with high-source impedances. The low input bias current allows the devices to be used for sensor interfaces, battery-supplied and portable applications, and active filtering.

The robust design of the TSV91x provides ease-of-use to the circuit designer. Features include a unity-gain stable, integrated RFI-EMI rejection filter, no phase reversal in overdrive condition, and high electrostatic discharge (ESD) protection (4-kV HBV).

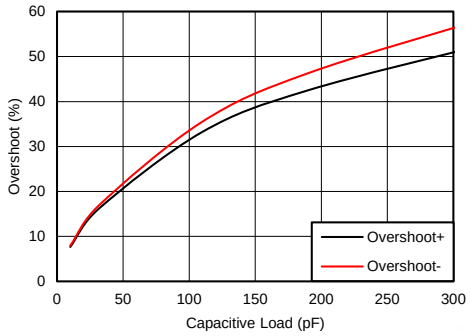
Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TSV911	SOT-23 (5) (2)	1.60 mm × 2.90 mm
TSV912	SOIC (8)	3.91 mm × 4.90 mm
	WSON (8) (2)	2.00 mm x 2.00 mm
TSV914	SOIC (14)	8.65 mm × 3.91 mm
	TSSOP (14) (2)	4.40 mm × 5.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) Package is preview only.

Small-Signal Overshoot vs Load Capacitance



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

Changes from Original (July 2017) to Revision A **Page**

- Changed TSV914 14-pin SOIC package from preview to production data in *Device Information* table ... 1
- Deleted TSV911 SC70, SOT-553 and SOIC packages from *Device Information* table ... 1
- Deleted TSV912 VSSOP packages from *Device Information* table ... 1
- Added 2017 copyright notice to Low-Side Motor Control ... 1
- Deleted TSV911 SC70 and SOIC packages from pinout drawings and *Pin Functions* table ... 4
- Deleted TSV912 DGK and DGS packages from pinout images *Pin Functions* table ... 5
- Deleted package preview note from TSV914 pinout drawing and *Pin Functions* table ... 6
- Added TSV914 *Thermal Information* table ... 8
- Added 2017 copyright notice to Figure 35 ... 19

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5 Device Comparison Table

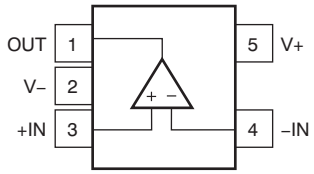
DEVICE	NO. OF CHANNELS	PACKAGE LEADS			
		DBV(1)	D	DSG(1)	PW(1)
TSV911 (2)	1	5	—	—	—
TSV912	2	—	8	8	—
TSV914	4	—	14	—	14

(1) Package preview
(2) Device preview

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6 Pin Configuration and Functions

TSV911 DBV Package (1)
5-Pin SOT-23
Top View



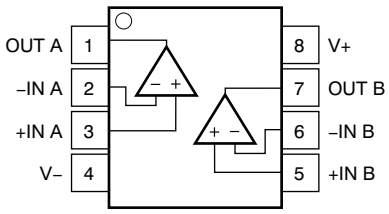
(1) Package preview

Pin Functions: TSV911

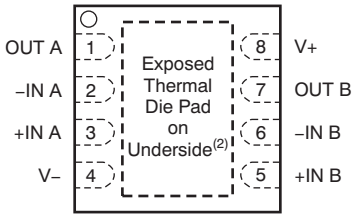
PIN		I/O	DESCRIPTION
NAME	NO.		
–IN	4	I	Inverting input
+IN	3	I	Noninverting input
OUT	1	O	Output
V–	2	—	Negative (lowest) supply or ground (for single-supply operation)
V+	5	—	Positive (highest) supply

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TSV912 D Package (1)
8-Pin SOIC, VSSOP
Top View



TSV912 DSG Package (1)
8-Pin WSON With Exposed Thermal Pad
Top View



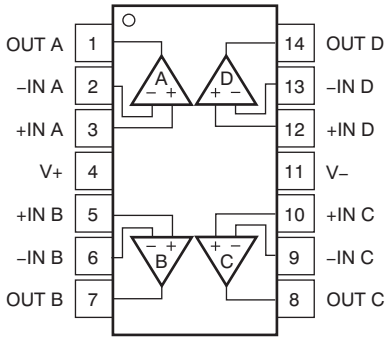
(1) Package preview

Pin Functions: TSV912

PIN		I/O	DESCRIPTION
NAME	NO.		
–IN A	2	I	Inverting input, channel A
+IN A	3	I	Noninverting input, channel A
–IN B	6	I	Inverting input, channel B
+IN B	5	I	Noninverting input, channel B
OUT A	1	O	Output, channel A
OUT B	7	O	Output, channel B
V–	4	—	Negative (lowest) supply or ground (for single-supply operation)
V+	8	—	Positive (highest) supply

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TSV914 D, PW Packages
14-Pin SOIC, TSSOP
Top View



Pin Functions: TSV914

PIN		I/O	DESCRIPTION
NAME	NO.		
–IN A	2	I	Inverting input, channel A
+IN A	3	I	Noninverting input, channel A
–IN B	6	I	Inverting input, channel B
+IN B	5	I	Noninverting input, channel B
–IN C	9	I	Inverting input, channel C
+IN C	10	I	Noninverting input, channel C
–IN D	13	I	Inverting input, channel D
+IN D	12	I	Noninverting input, channel D
OUT A	1	O	Output, channel A
OUT B	7	O	Output, channel B
OUT C	8	O	Output, channel C
OUT D	14	O	Output, channel D
V–	11	—	Negative (lowest) supply or ground (for single-supply operation)
V+	4	—	Positive (highest) supply

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)(1)

			MIN	MAX	UNIT
Supply voltage				6	V
Signal input pins	Voltage(2)	Common-mode	(V–) – 0.5	(V+) + 0.5	V
		Differential		(V_+) – (V–) + 0.2	
	Current(2)		–10	10	mA
Output short-circuit(3)			Continuous		mA
Specified, T_A			–40	125	°C
Junction, T_J				150	
Storage, T_{stg}			–65	150	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Input pins are diode-clamped to the power-supply rails. Current limit input signals that can swing more than 0.5 V beyond the supply rails to 10 mA or less.
(3) Short-circuit to ground, one amplifier per package.

7.2 ESD Ratings

over operating free-air temperature range (unless otherwise noted)

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±4000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101(2)	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_S	Supply voltage	2.5	5.5	V
	Specified temperature	–40	125	°C

7.4 Thermal Information: TSV912

THERMAL METRIC(1)		TSV912 D (SOIC) 8 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	157.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	104.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	99.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter	55.6	°C/W
ψ_{JB}	Junction-to-board characterization parameter	99.2	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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7.5 Thermal Information: TSV914

THERMAL METRIC[1]		TSV914 D (SOIC) 14 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	106.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	69	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	63	°C/W
ψ_{JT}	Junction-to-top characterization parameter	25.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	62.7	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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7.6 Electrical Characteristics: V_S (Total Supply Voltage) = (V+) – (V–) = 2.5 V to 5.5 V

at T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
V_{OS}	Input offset voltage	V_S = 5 V		±0.3	±1.5	mV
		V_S = 5 V T_A = –40°C to 125°C			±3	
dV_{OS}/dT	Drift	V_S = 5 V T_A = –40°C to 125°C		±0.5		µV/°C
PSRR	Power-supply rejection ratio	V_S = 2.5 V – 5.5 V, V_{CM} = (V–)		±7		µV/V
	Channel separation, DC	At DC		100		dB
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage range	V_S = 2.5 V to 5.5 V	(V–) – 0.1		(V+) + 0.1	V
CMRR	Common-mode rejection ratio	V_S = 5.5 V (V–) – 0.1 V < V_{CM} < (V+) – 1.4 V T_A = –40°C to 125°C	80	103		dB
		V_S = 5.5 V, V_{CM} = –0.1 V to 5.6 V T_A = –40°C to 125°C	57	87		
		V_S = 2.5 V, (V–) – 0.1 V < V_{CM} < (V+) – 1.4 V T_A = –40°C to 125°C		88		
		V_S = 2.5 V, V_{CM} = –0.1 V to 1.9 V T_A = –40°C to 125°C		81		
INPUT BIAS CURRENT						
I_B	Input bias current			±1		pA
I_{OS}	Input offset current			±0.05		pA
NOISE						
E_n	Input voltage noise (peak-to-peak)	V_S = 5 V, f = 0.1 Hz to 10 Hz		4.77		μV_{PP}
e_n	Input voltage noise density	V_S = 5 V, f = 10 kHz		12		$nV/\sqrt{Hz}$
		V_S = 5 V, f = 1 kHz		18		$nV/\sqrt{Hz}$
i_n	Input current noise density	f = 1 kHz		10		$fA/\sqrt{Hz}$
INPUT CAPACITANCE						
C_{ID}	Differential			2		pF
C_{IC}	Common-mode			4		pF
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	V_S = 2.5 V, (V–) + 0.04 V < V_O < (V+) – 0.04 V R_L = 10 kΩ		100		dB
		V_S = 5.5 V, (V–) + 0.05 V < V_O < (V+) – 0.05 V R_L = 10 kΩ	104	130		
		V_S = 2.5 V, (V–) + 0.06 V < V_O < (V+) – 0.06 V R_L = 2 kΩ		100		
		V_S = 5.5 V, (V–) + 0.15 V < V_O < (V+) – 0.15 V R_L = 2 kΩ		130		
FREQUENCY RESPONSE						
GBP	Gain bandwidth product	V_S = 5 V, G = 1		8		MHz
φ_m	Phase margin	V_S = 5 V, G = 1		55		Degrees
SR	Slew rate	V_S = 5 V, G = 1 R_L = 2 kΩ C_L = 100 pF		4.5		V/µs
t_S	Settling time	To 0.1%, V_S = 5 V, 2-V step , G = 1 C_L = 100 pF		0.5		µs
		To 0.01%, V_S = 5 V, 2-V step , G = 1 C_L = 100 pF		1		
t_{OR}	Overload recovery time	V_S = 5 V, V_{IN} × gain > V_S		0.2		µs
THD + N	Total harmonic distortion + noise(1)	V_S = 5 V, V_O = 1 V_{RMS}, G = 1, f = 1 kHz		0.0008%		
OUTPUT						
V_O	Voltage output swing from supply rails	V_S = 5.5 V, R_L = 10 kΩ			15	mV
		V_S = 5.5 V, R_L = 2 kΩ			50	

(1) Third-order filter; bandwidth = 80 kHz at –3 dB.

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Electrical Characteristics: V_S (Total Supply Voltage) = (V+) – (V–) = 2.5 V to 5.5 V (continued)

at T_A = 25°C, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{SC}	Short-circuit current	V_S = 5 V		±50		mA
Z_O	Open-loop output impedance	V_S = 5 V, f = 10 MHz		100		Ω
POWER SUPPLY						
I_Q	Quiescent current per amplifier	V_S = 5.5 V, I_O = 0 mA		550	750	µA
		V_S = 5.5 V, I_O = 0 mAT_A = –40°C to 125°C			1100	

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7.7 Typical Characteristics

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

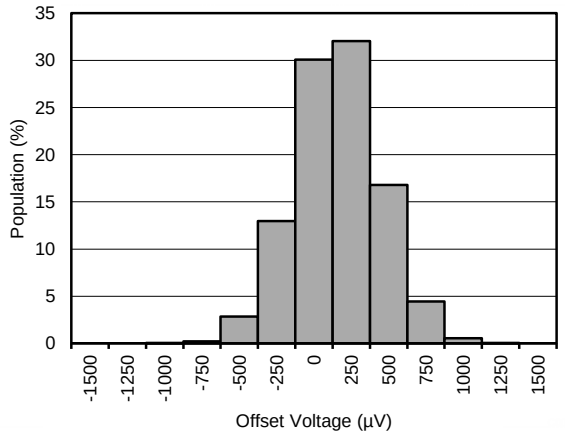
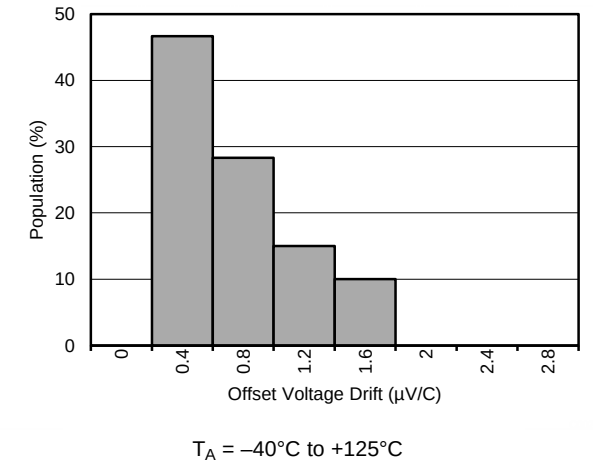


Figure 1. Offset Voltage Production Distribution



T_A = –40°C to +125°C

Figure 2. Offset Voltage Drift Distribution

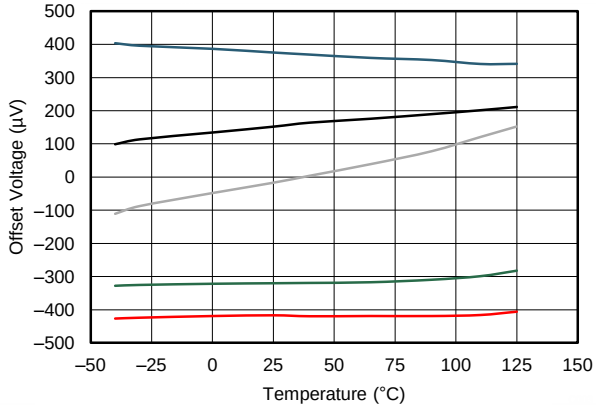
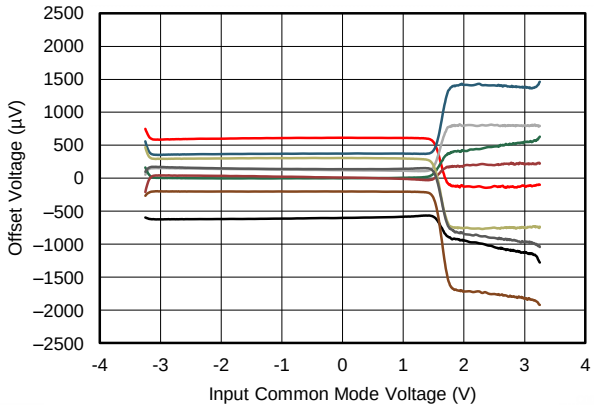
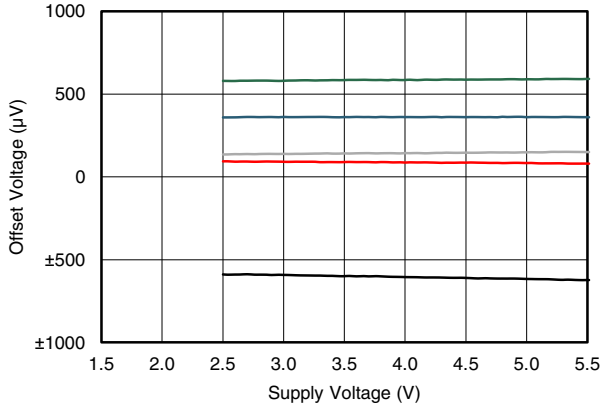


Figure 3. Offset Voltage vs Temperature



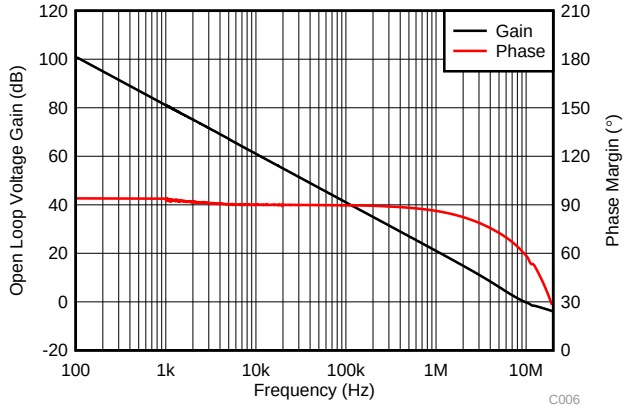
V+ = 2.75 V, V– = –2.75 V

Figure 4. Offset Voltage vs Common-Mode Voltage



V_S = 2.5 V to 5.5 V

Figure 5. Offset Voltage vs Power Supply



C_L = 10 pF

Figure 6. Open-Loop Gain and Phase vs Frequency

Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

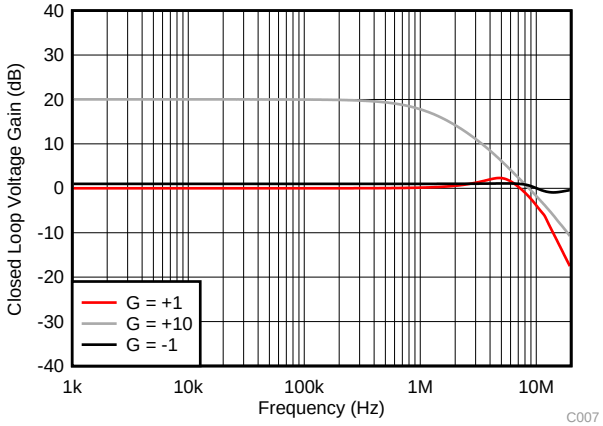


Figure 7. Closed-Loop Gain vs Frequency

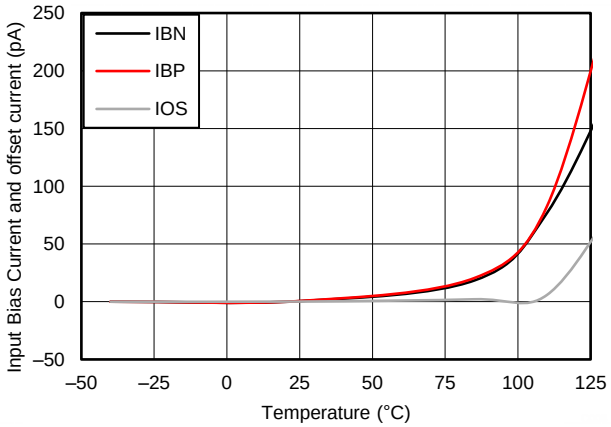


Figure 8. Input Bias Current vs Temperature

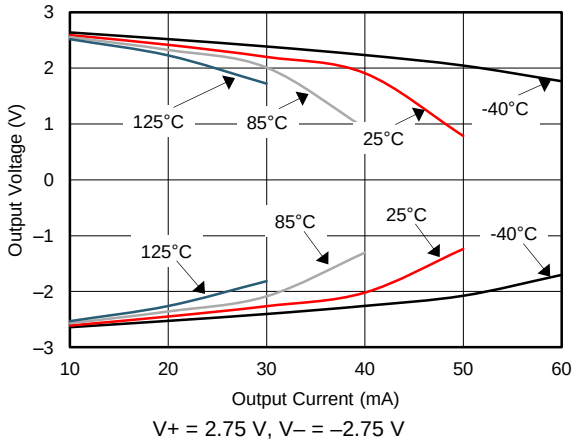


Figure 9. Output Voltage Swing vs Output Current

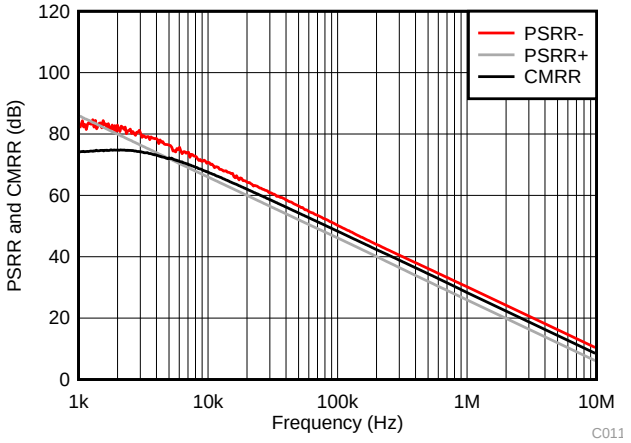


Figure 10. CMRR and PSRR vs Frequency (Referred to Input)

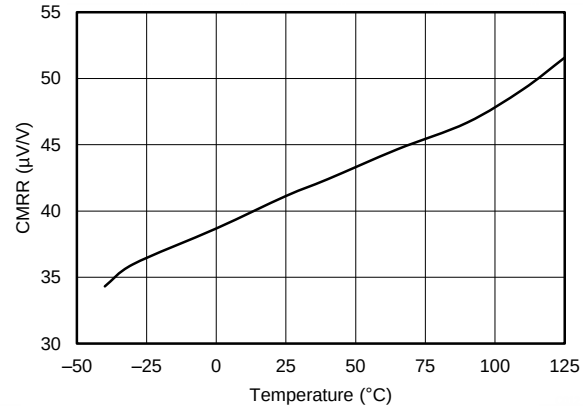


Figure 11. CMRR vs Temperature

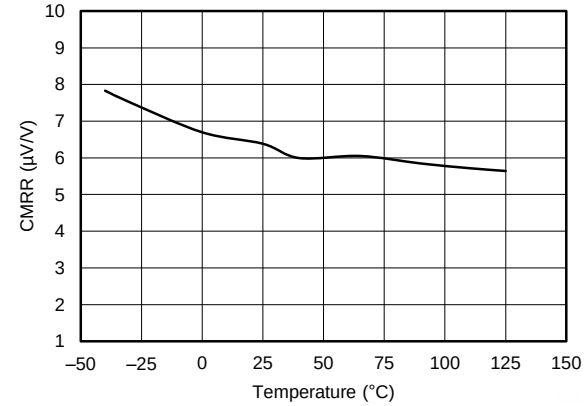
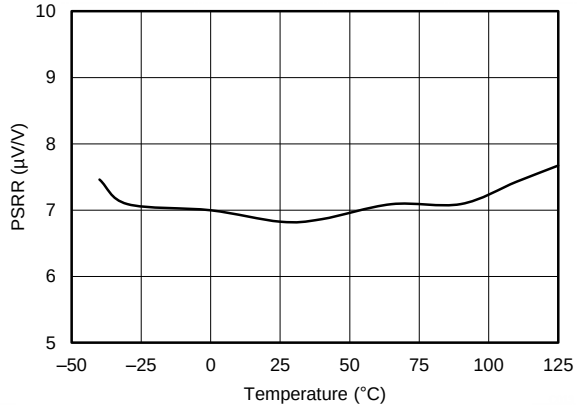


Figure 12. CMRR vs Temperature

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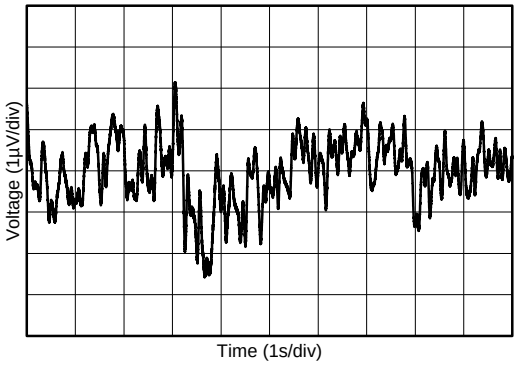
Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)



V_S = 2.5 V to 5.5 V

Figure 13. PSRR vs Temperature



V_S = 2.5 V to 5.5 V

Figure 14. 0.1-Hz to 10-Hz Input Voltage Noise

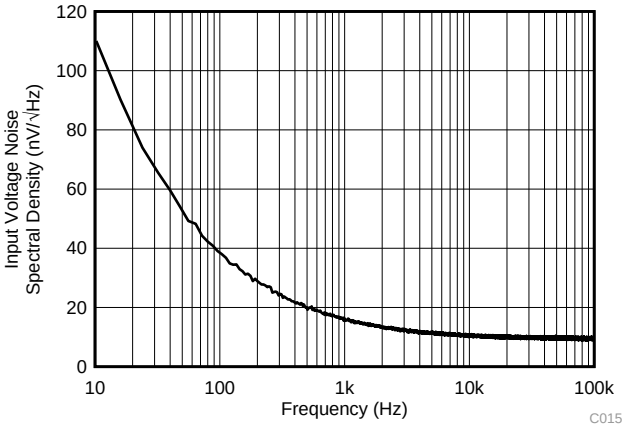
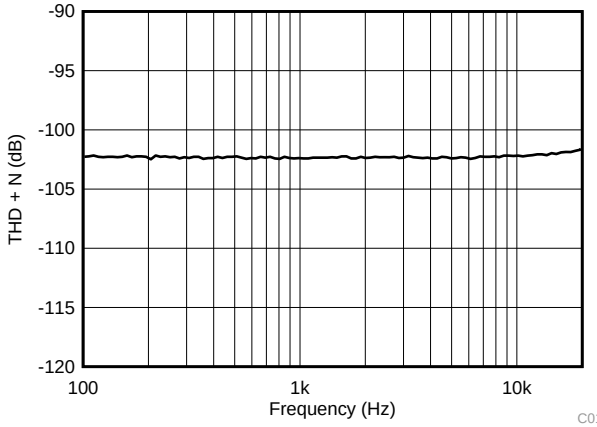
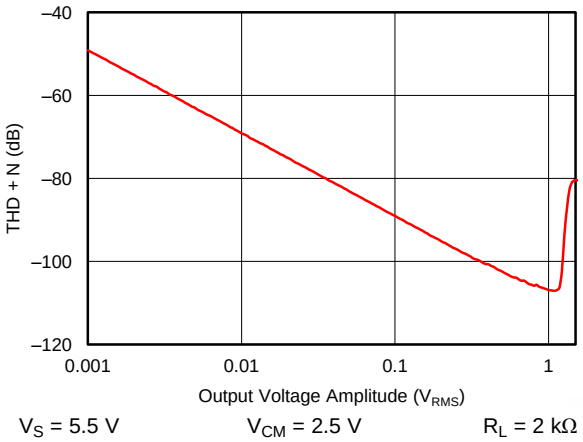


Figure 15. Input Voltage Noise Spectral Density vs Frequency



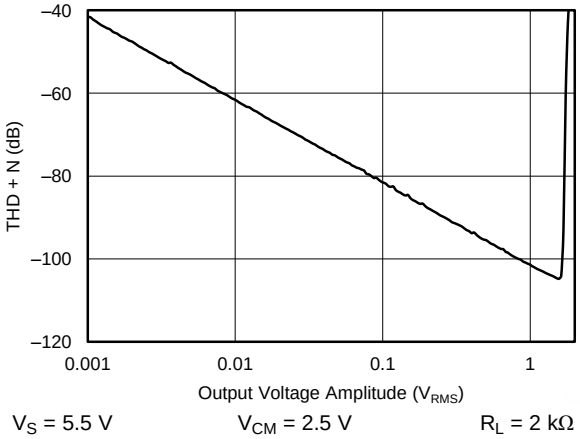
V_S = 5.5 V | V_{CM} = 2.5 V | R_L = 2 kΩ
G = 1 | V_{OUT} = 0.5 V_{RMS} | BW = 80 kHz

Figure 16. THD + N vs Frequency



V_S = 5.5 V | V_{CM} = 2.5 V | R_L = 2 kΩ
G = 1 | BW = 80 kHz | f = 1 kHz

Figure 17. THD + N vs Amplitude



V_S = 5.5 V | V_{CM} = 2.5 V | R_L = 2 kΩ
G = –1 | BW = 80 kHz | f = 1 kHz

Figure 18. THD + N vs Amplitude

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Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

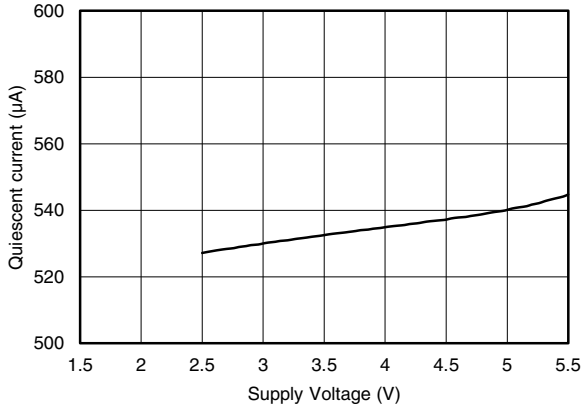


Figure 19. Quiescent Current vs Supply Voltage

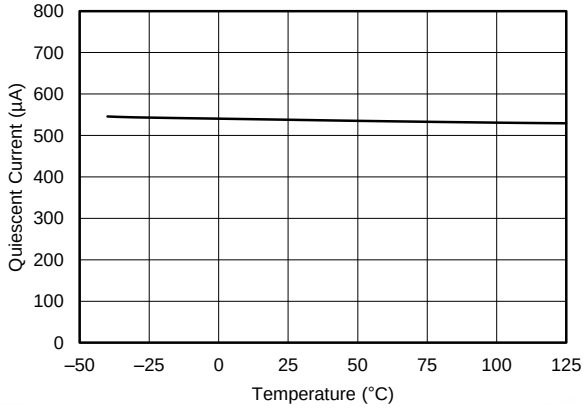


Figure 20. Quiescent Current vs Temperature

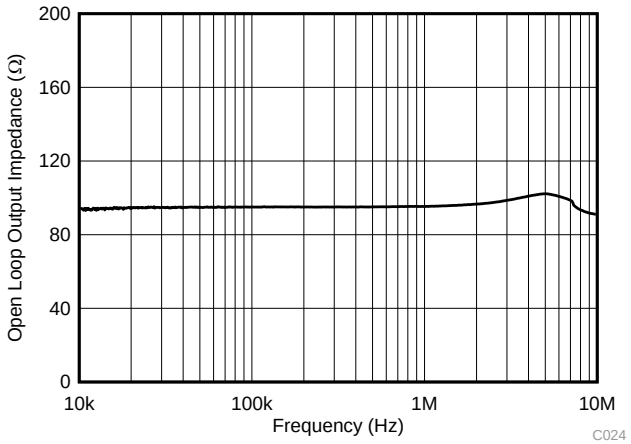
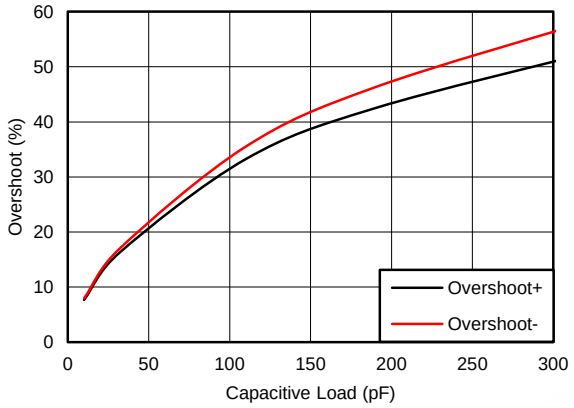
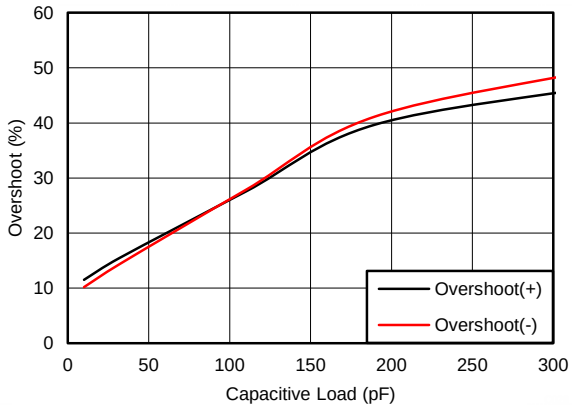


Figure 21. Open-Loop Output Impedance vs Frequency



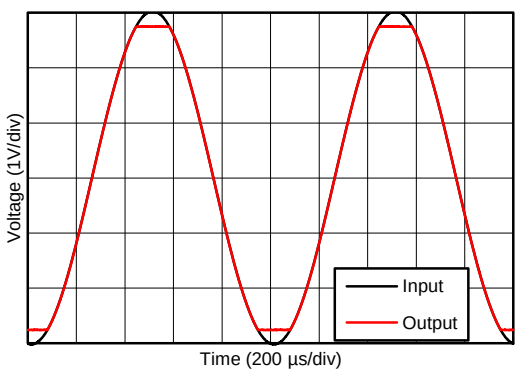
V+ = 2.75 V V– = –2.75 V G = 1 V/V
R_L = 10 kΩ V_{OUT} step = 100 mV_{p-p}

Figure 22. Small-Signal Overshoot vs Load Capacitance



V+ = 2.75 V V– = –2.75 V R_L = 10 kΩ
G = –1 V/V V_{OUT} step = 100 mV_{p-p}

Figure 23. Small-Signal Overshoot vs Load Capacitance



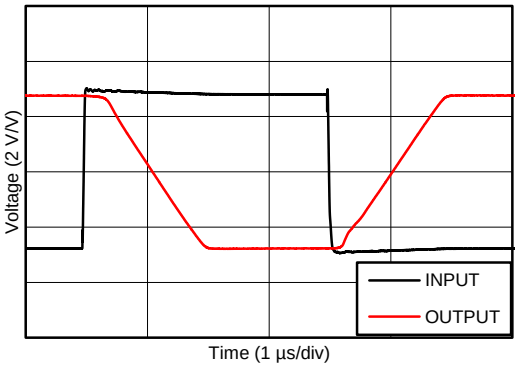
V+ = 2.75 V, V– = –2.75 V

Figure 24. No Phase Reversal

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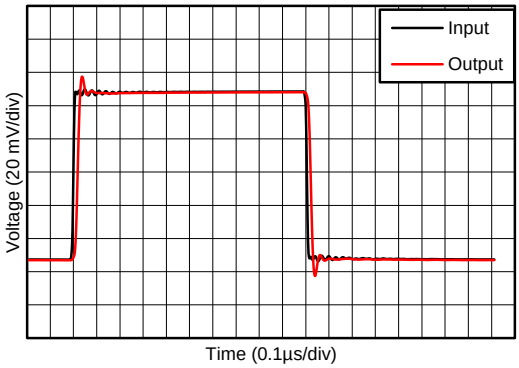
Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)



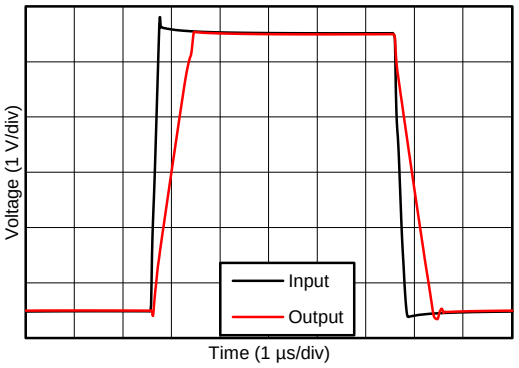
V+ = 2.75 V, V– = –2.75 V , G = –10 V/V

Figure 25. Overload Recovery



V+ = 2.75 V, V– = –2.75 V, G = 1 V/V

Figure 26. Small-Signal Step Response



V+ = 2.75 V V– = –2.75 V C_L = 100 pF
G = 1 V/V

Figure 27. Large-Signal Step Response

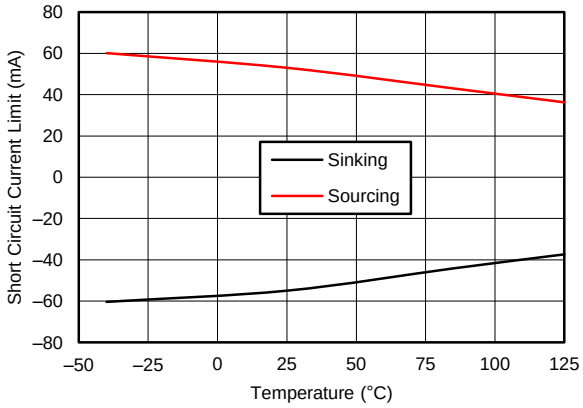
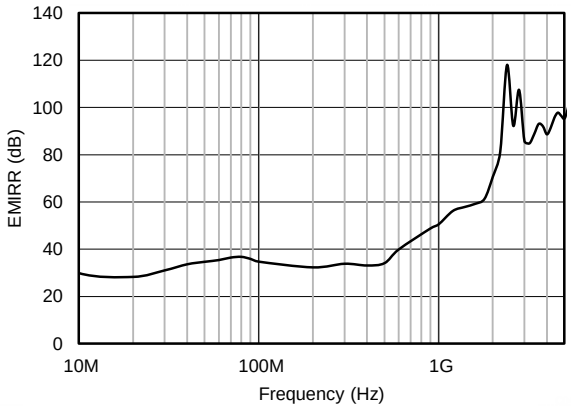
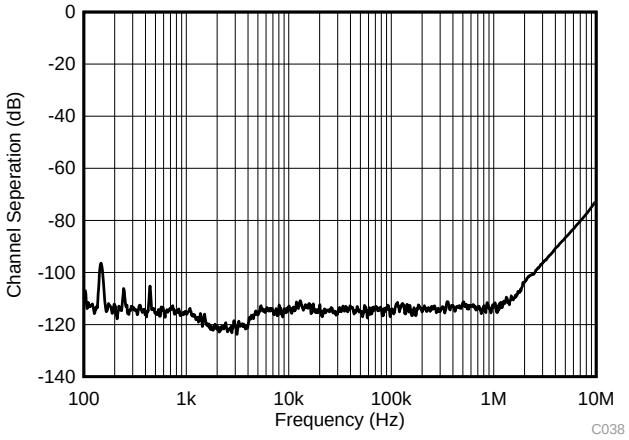


Figure 28. Short-Circuit Current vs Temperature



P_{RF} = –10 dBm

Figure 29. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR+) vs Frequency



V+ = 2.75 V, V– = –2.75 V

Figure 30. Channel Separation vs Frequency

Typical Characteristics (continued)

at T_A = 25°C, V_S = 5.5 V, R_L = 10 kΩ connected to V_S / 2, V_{CM} = V_S / 2, and V_{OUT} = V_S / 2 (unless otherwise noted)

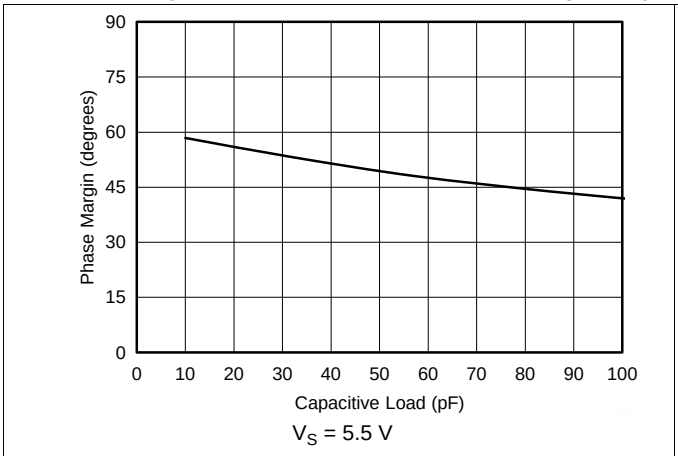


Figure 31. Phase Margin vs Capacitive Load

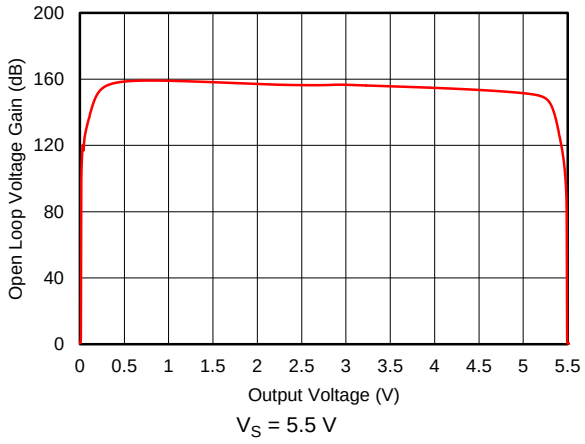


Figure 32. Open Loop Voltage Gain vs Output Voltage

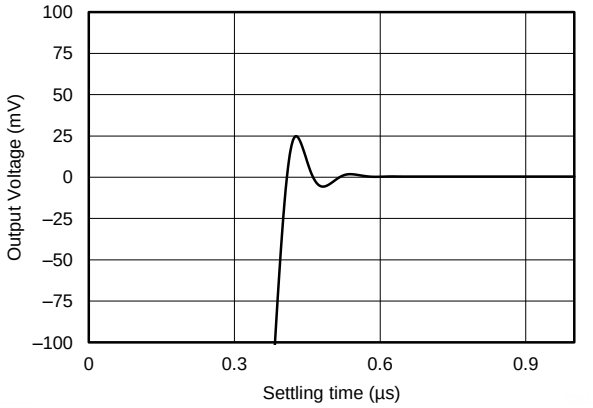


Figure 33. Large Signal Settling Time (Positive)

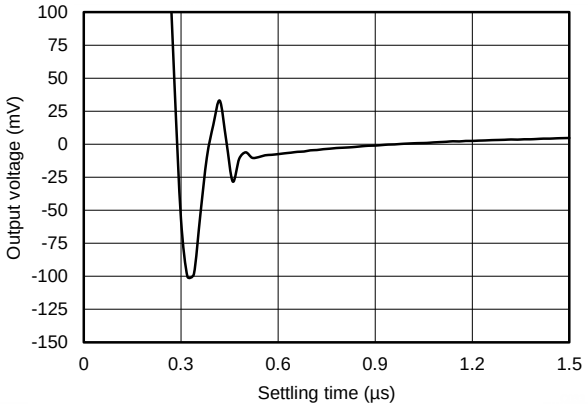


Figure 34. Large Signal Settling Time (Negative)

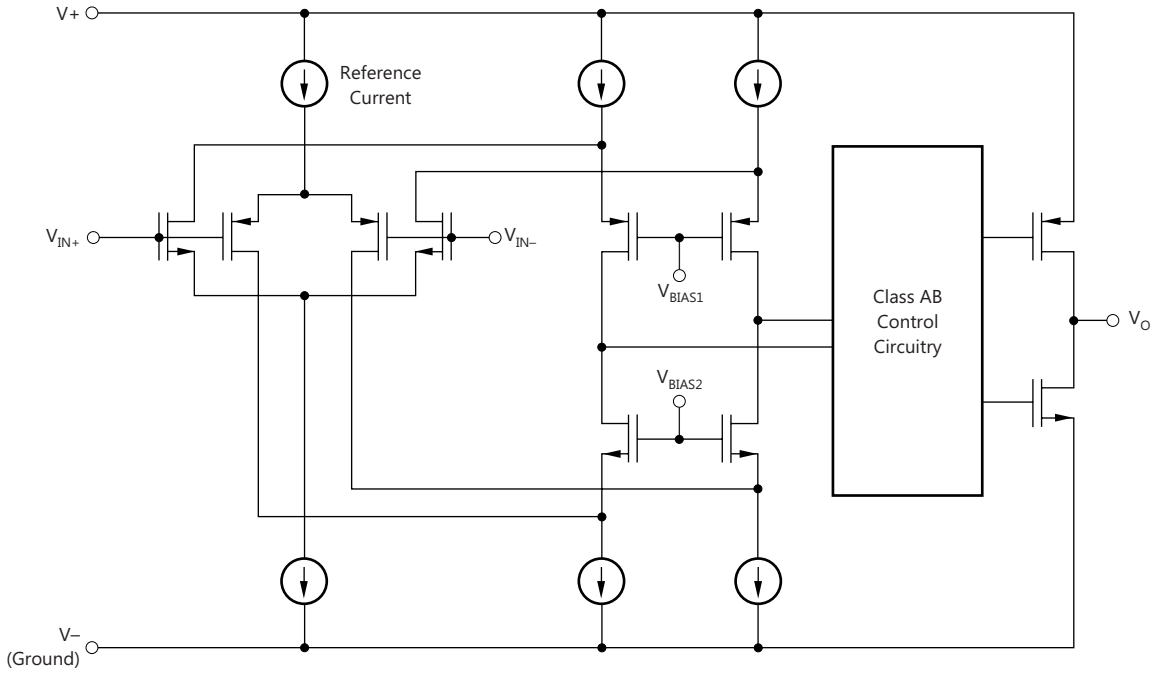
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8 Detailed Description

8.1 Overview

The TSV91x series is a family of low-power, rail-to-rail input and output op amps. These devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose applications. The input common-mode voltage range includes both rails and allows the TSV91x series to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications and are designed for driving sampling analog-to-digital converters (ADCs).

8.2 Functional Block Diagram



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8.3 Feature Description

8.3.1 Rail-to-Rail Input

The input common-mode voltage range of the TSV91x family extends 100 mV beyond the supply rails for the full supply voltage range of 2.5 V to 5.5 V. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as shown in the *Functional Block Diagram*. The N-channel pair is active for input voltages close to the positive rail, typically (V+) – 1.4 V to 100 mV above the positive supply, whereas the P-channel pair is active for inputs from 100 mV below the negative supply to approximately (V+) – 1.4 V. There is a small transition region, typically (V+) – 1.2 V to (V+) – 1 V, in which both pairs are on. This 200-mV transition region can vary up to 200 mV with process variation. Thus, the transition region (with both stages on) can range from (V+) – 1.4 V to (V+) – 1.2 V on the low end, and up to (V+) – 1 V to (V+) – 0.8 V on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD can degrade compared to device operation outside this region.

8.3.2 Rail-to-Rail Output

Designed as a low-power, low-voltage operational amplifier, the TSV91x series delivers a robust output drive capability. A class AB output stage with common-source transistors achieves full rail-to-rail output swing capability. For resistive loads of 10 kΩ, the output swings to within 15 mV of either supply rail, regardless of the applied power-supply voltage. Different load conditions change the ability of the amplifier to swing close to the rails.

8.3.3 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output devices of the operational amplifier enter a saturation region when the output voltage exceeds the rated operating voltage, because of the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return to the linear state. After the charge carriers return to the linear state, the device begins to slew at the specified slew rate. Therefore, the propagation delay (in case of an overload condition) is the sum of the overload recovery time and the slew time. The overload recovery time for the TSV91x series is approximately 200 ns.

8.4 Device Functional Modes

The TSV91x family has a single functional mode. These devices are powered on as long as the power-supply voltage is between 2.5 V (±1.25 V) and 5.5 V (±2.75 V).

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9 Application and Implementation

NOTE

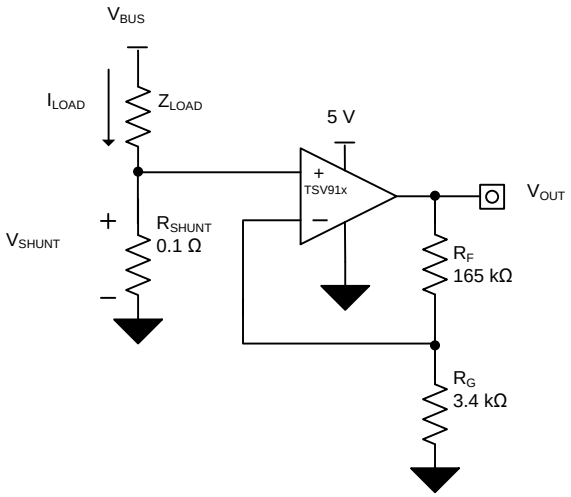
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TSV91x series features 8-MHz bandwidth and 4.5-V/µs slew rate with only 550-µA of supply current per channel, providing good AC performance at low power consumption. DC applications are well served with a low input noise voltage of 18 nV / $\sqrt{\text{Hz}}$ at 1 kHz, low input bias current, and a typical input offset voltage of 0.3 mV.

9.2 Typical Application

Figure 35 shows the TSV91x configured in a low-side, motor-control application.



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Figure 35. TSV91x in a Low-Side, Motor-Control Application

9.2.1 Design Requirements

The design requirements for this design are:

- Load current: 0 A to 1 A
- Output voltage: 4.95 V
- Maximum shunt voltage: 100 mV

Typical Application (continued)

9.2.2 Detailed Design Procedure

The transfer function of the circuit in Figure 35 is shown in Equation 1

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times Gain \quad (1)$$

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is defined using Equation 2.

$$R_{SHUNT} = \frac{V_{SHUNT_MAX}}{I_{LOAD_MAX}} = \frac{100mV}{1A} = 100m\Omega \quad (2)$$

Using Equation 2, R_{SHUNT} is 100 mΩ. The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the TSV91x to produce an output voltage of approximately 0 V to 4.95 V. The gain required by the TSV91x to produce the necessary output voltage is calculated using Equation 3:

$$Gain = \frac{\left(V_{OUT_MAX} - V_{OUT_MIN}\right)}{\left(V_{IN_MAX} - V_{IN_MIN}\right)} \quad (3)$$

Using Equation 3, the required gain is calculated to be 49.5 V/V, which is set with resistors R_F and R_G. Equation 4 is used to size the resistors, R_F and R_G, to set the gain of the TSV91x to 49.5 V/V.

$$Gain = 1 + \frac{\left(R_F\right)}{\left(R_G\right)} \quad (4)$$

Selecting R_F as 165 kΩ and R_G as 3.4 kΩ provides a combination that equals roughly 49.5 V/V. Figure 36 shows the measured transfer function of the circuit shown in Figure 35.

9.2.3 Application Curve

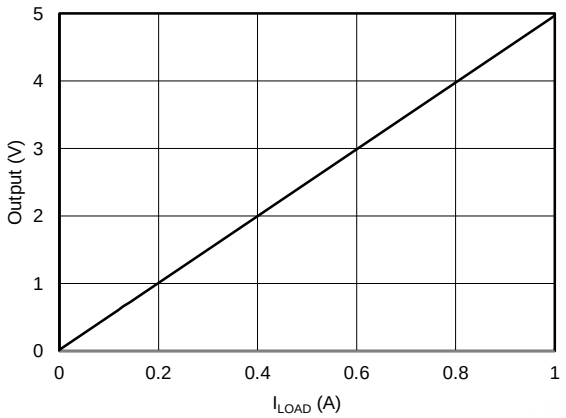


Figure 36. Low-Side, Current-Sense, Transfer Function

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10 Power Supply Recommendations

The TSV91x series is specified for operation from 2.5 V to 5.5 V (±1.25 V to ±2.75 V); many specifications apply from –40°C to +125°C. The *Typical Characteristics* section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 6 V can permanently damage the device; see the *Absolute Maximum Ratings* table.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the section.

10.1 Input and ESD Protection

The TSV91x series incorporates internal ESD protection circuits on all pins. For input and output pins, this protection consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10-mA, as stated in the *Absolute Maximum Ratings* table. Figure 37 shows how a series input resistor is added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.

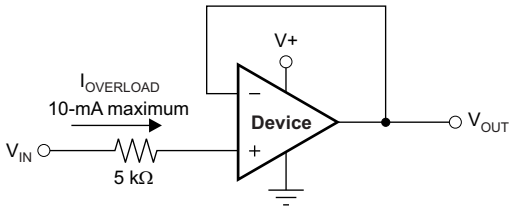


Figure 37. Input Current Protection

11 Layout

11.1 Layout Guidelines

For best operational performance of the device, use good printed-circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and of op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see *Circuit Board Layout Techniques*.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As shown in Figure 39, keeping RF and RG close to the inverting input minimizes parasitic capacitance on the inverting input.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is recommended to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

11.2 Layout Example

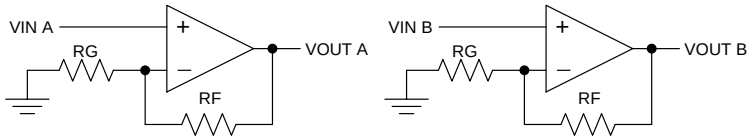


Figure 38. Schematic Representation for Figure 39

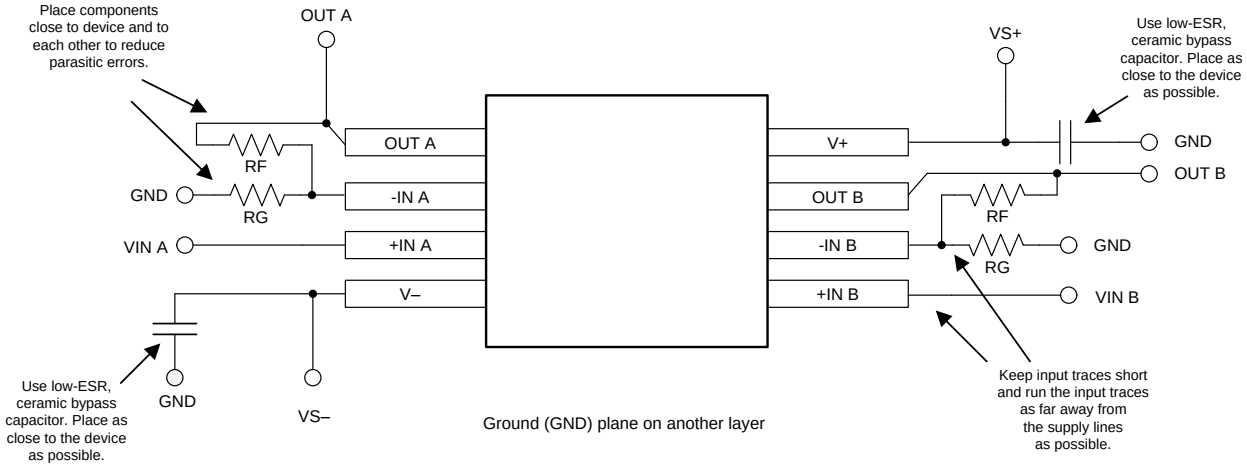


Figure 39. Layout Example

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12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

Circuit Board Layout Techniques

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TSV911	Click here	Click here	Click here	Click here	Click here
TSV912	Click here	Click here	Click here	Click here	Click here
TSV914	Click here	Click here	Click here	Click here	Click here

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.5 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TSV912AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	TSV912	Samples
TSV914AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPD	Level-2-260C-1 YEAR	-40 to 125	TSV914AD	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

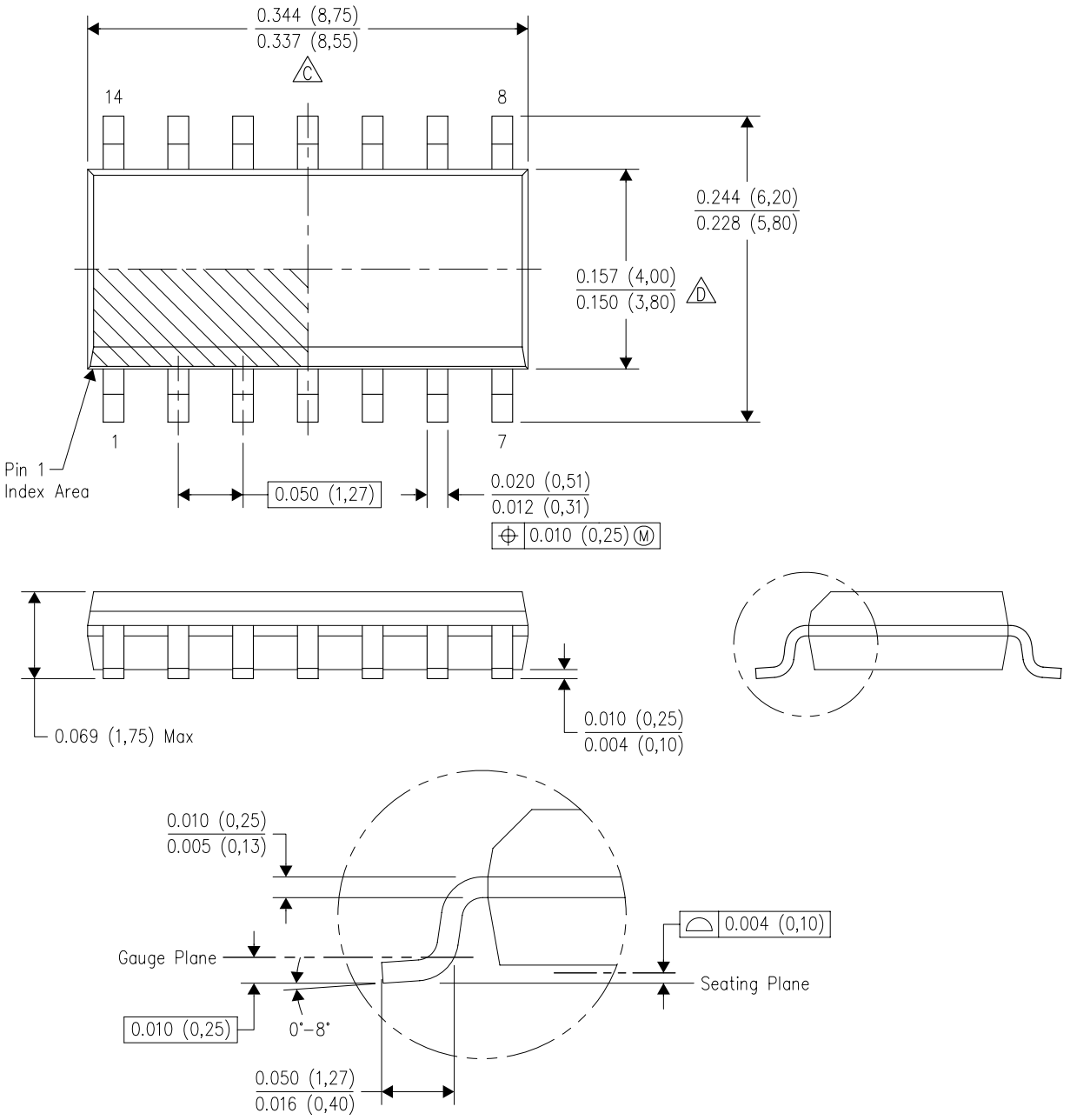
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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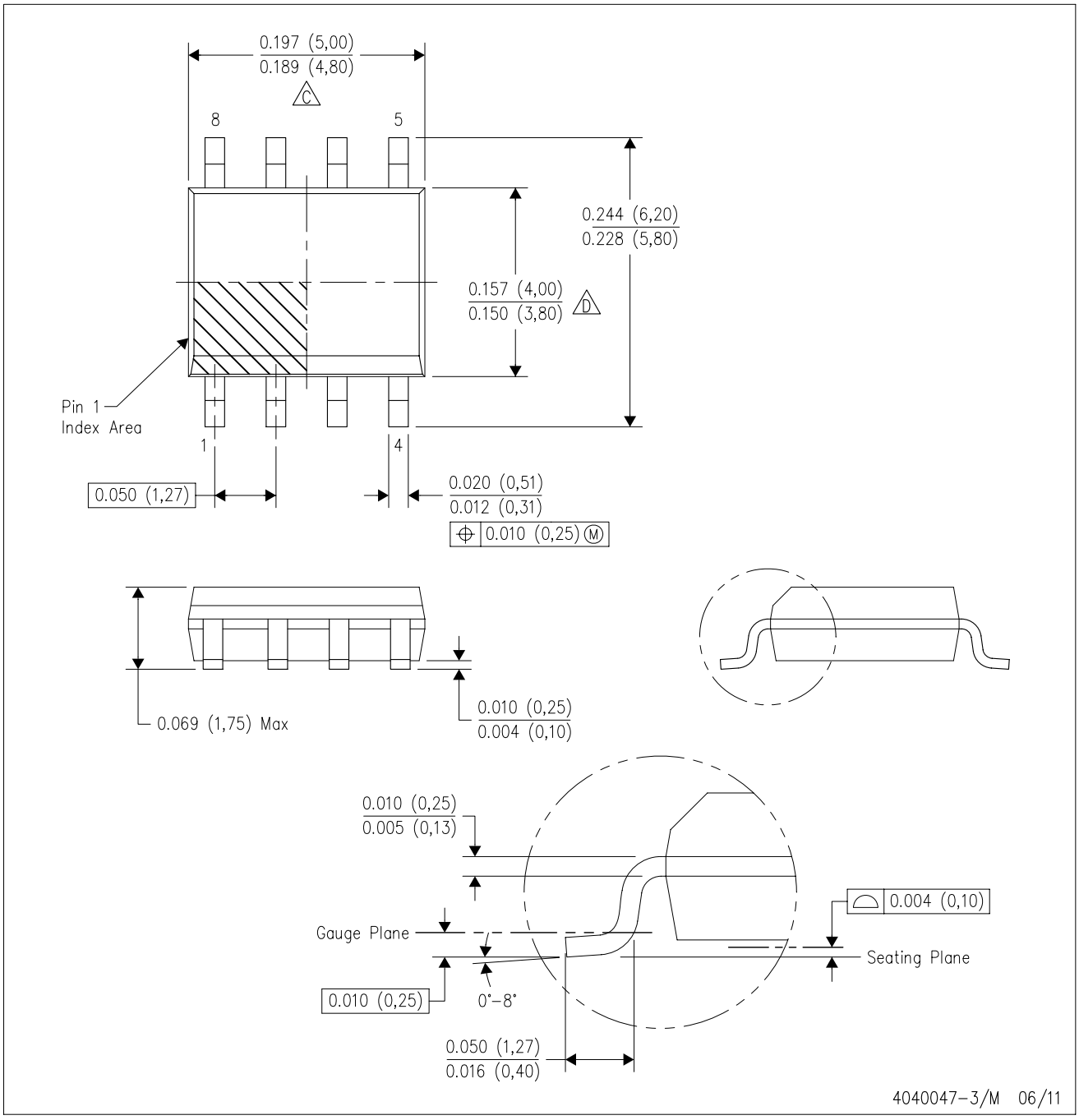
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
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C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
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